

**Sharif University of Technology**

# **Power Amplifier**

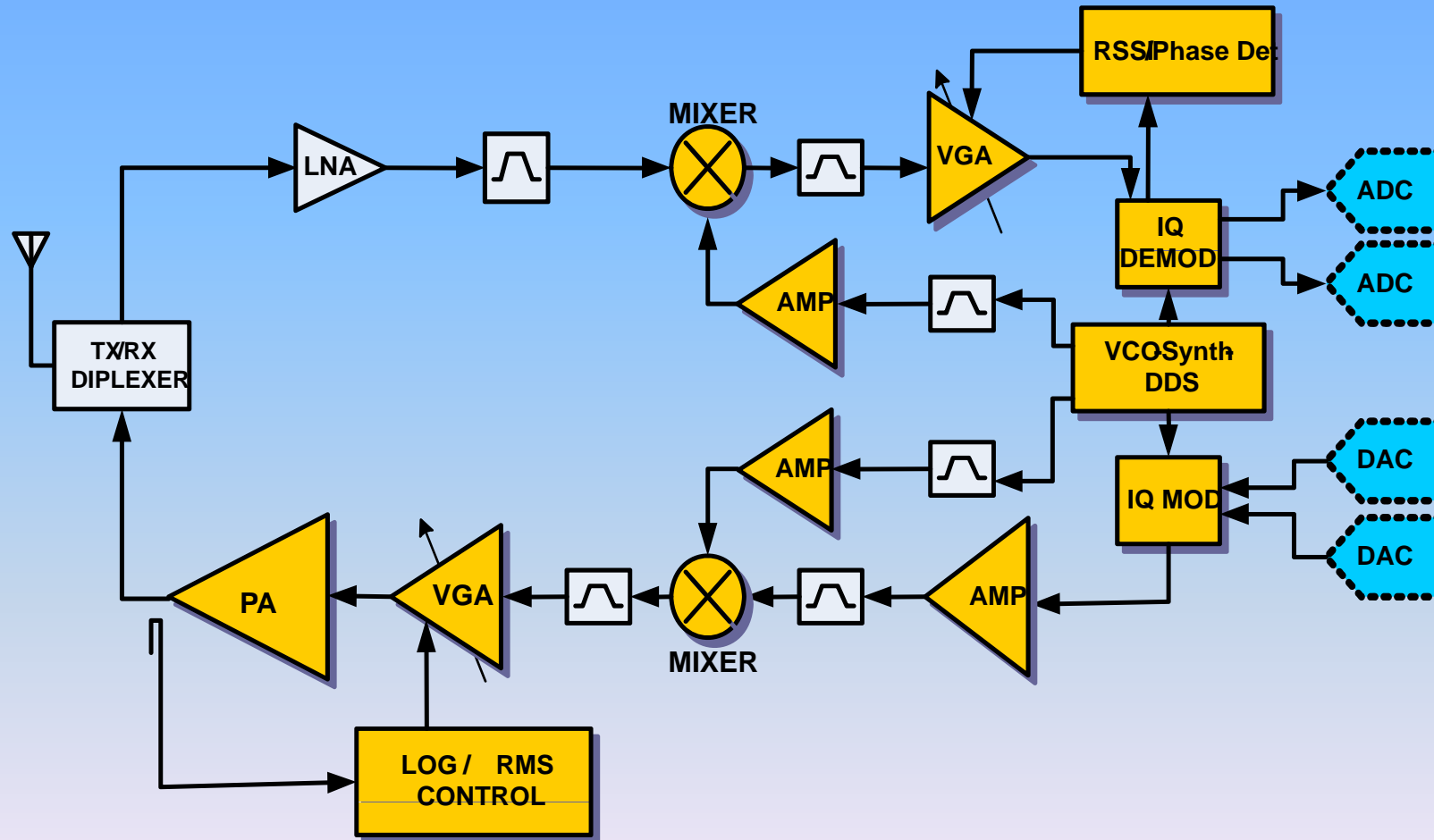
**Instructor:**

**Dr. Ali Medi**

# Outline

- **Introduction**
- **Some Important Definitions**
- **PA Classes**
  - **Linear**
  - **Non-linear**
- **Linearization Techniques**
- **Conclusion**

# System Schematic



# PA Specifications

- **Gain (Gain Flatness)**
- **Power consumption**
- **Linearity**
- **Signal peak to mean ratio**
- **Bandwidth**
- **Frequency band (transmit and receive)**
- **Power delivered**
- **Permissible in-band emission**
- **Permissible out-of-band emission**
- **Stability over VSWR**
  - Ability to transmit into unknown/varying load
- **Efficiency**
  - Minimize any lose in the form of heat & noise
- **Size**
  - Find the minimum size as much as possible

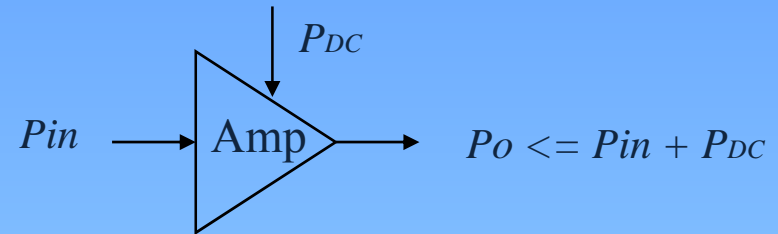
# Peak Output Power

- **Determines the range for two-way communications**
- **Often specified at the 1-dB compression point**
- **Some examples:**
  - **Need about 1-2 W for cellular handsets (~1 km distance)**
  - **Need about 100mW for W-LAN (100 m)**
  - **Need about 10mW for W-PAN (Bluetooth) (1-10 m)**
  - **Need about 1mW for UWB and sensor networks**
- **The average power transmitted may be much lower**
  - **Power control (slow time scale)**
  - **Amplitude modulation**

# Efficiency

- **Remember- COST is major driving factor!**
- **The associated power supply and heat sink can be incredibly expensive**
- **For lower power systems, (below 10mw) ,power consumption of other block is important too**

# Efficiency Measurement



- **Drain Efficiency**
  - $P_{OUT}$  includes harmonics power
- **Power Added Efficiency**
  - Account drive power
  - Could be negative for low gain!
- **Total efficiency**
- **When power gain is high**

$$\eta_D = \frac{P_{out}}{P_{dc}}$$

$$\eta_{PA} = \frac{P_{OUT} - P_{IN}}{P_{DC}} = \eta_D \cdot \left(1 - \frac{1}{G}\right)$$

$$\eta_{total} = \frac{P_o}{P_{DC} + P_{in}}$$

$$\eta_{PAE} \approx \eta_c \approx \eta_{total}$$

# High PAPR

- **There are some ways ,such that...**
  - **Drain modulation**
  - **Load modulation**
  - **RF PWM**
    - **In low frequency**
    - **BUT, broadband**
- **Some linearization schemes may reduce the overall efficiency!!!**



# Signal Types

- **There are two categories including:**
  - **Constant-envelope**
    - **Data is in phase or frequency**
    - **Non-linear PA can be used**
    - **Abrupt frequency or phase transitions**
      - **Sinc-function spectrum**
        - » **Spreads signal energy over a wide BW**
        - » **Data rate will be reduced**
  - **Non-constant envelope**
    - **Linear PA should be used**
    - **Data is in envelope, too**
    - **Higher data rate**

# Constant Envelope Modulation

- **Information encoded in phase/frequency only**
  - **GMSK,FSK**
- **Power efficient amplification**  
**BUT, spectrally inefficient**

# Non-Constant Envelope Modulation

- **Information encoded in both amplitude and phase**
  - QPSK, QAM, CDMA
- **Spectral efficient ,  
BUT power inefficient!**

# PAPR

- **Peak to average Power Ratio**
  - Peak power over average power
  
- **PAPR is a strong function of the type of modulation**

# Average Efficiency

- **Important for non-constant envelope**
  - There is time-varying instantaneous efficiency

$$\eta_{AVG} = \frac{P_{outAVG}}{P_{inAVG}}$$

- **Modern systems uses power control**
  - Uses as low as possible power

# Basics of non-Linearity

- **Large signal behavior of the semiconductor devices is nonlinear**
  - **Power amplifiers are nonlinear systems**
- **Nonlinearity leads to**
  - **Generation of Harmonics**
  - **Intermodulation Distortion / Spectral Regrowth**
  - **SNR (NPR) Degradation**
  - **Constellation Deformation**

# Linearity Measurement

- **Some ways to measure non-linearity:**
  - **ACPR (Adjacent Channel Power Ratio)**
  - **EVM (Error Vector Magnitude)**
  - **Spectral Mask**
  - **$P_{1dB}$**
  - **C/I**
  - **NPR (Noise-Power Ratio)**

# AM-AM distortion

**System transfer function:**

$$y(t) = \alpha_1 x(t) + \alpha_2 x^2(t) + \alpha_3 x^3(t) + \dots$$

**Input signal:**

$$x(t) = A(t) \cos(\omega t + \phi(t))$$

**Output signal:**

$$y(t) = g[A(t)] \cos(\omega t + \phi(t) + \psi[A(t)])$$

- **AM/AM conversion is dominated by  $g_m$  non-linearity**



# AM-PM Distortion

- **Phase shift associated with the signal amplitude**
- **Introduction of unwanted phase modulation into the output signal**
- **Phase modulation observed**
  - **Depending of the input amplitude**
- **AM-PM is often the result of voltage dependent capacitors**

# AM-PM Conversion

$$V_{out} = B(t) \cos(\omega t + \varphi(t))$$

$$C = C[V_{out}(t)] \Rightarrow \bar{C} \approx \overline{C[B(t)]}$$

$$\varphi(t) = \tan^{-1}(RC[B(t)]\omega)$$

$$\bar{\varphi} \approx \tan^{-1}(R\bar{C}\omega)$$

$\bar{C}$  = Average capacitor value at the first harmonic

$\bar{\varphi}$  = Average phase at the first harmonic

# TX Spectrum Mask

# ACPR

- **Adjacent (Alternate) Channel Power Ratio**
  - **Is the ratio of the power in a specified band outside the signal bandwidth to the rms power in the signal**
  - **Widely used with modern shaped pulse digital signals such as NADC and CDMA**

# EVM

- **Error Vector Magnitude**
  - A convenient measure of how nonlinearity interferes with the detection process
  - the distance between the desired and actual signal vectors, normalized to a fraction of the signal amplitude
    - both peak and rms errors are specified

$$EVM = \sqrt{\frac{\sum_{k=1}^M \|V(K) - R(K)\|^2}{\sum_{k=1}^M \|R(K)\|^2}}$$

$$EVM = \sqrt{\frac{\sum_{k=1}^M \|V(K) - R(K)\|^2}{\sum_{k=1}^M \|R(K)\|^2}}$$

# Constellation Deformation

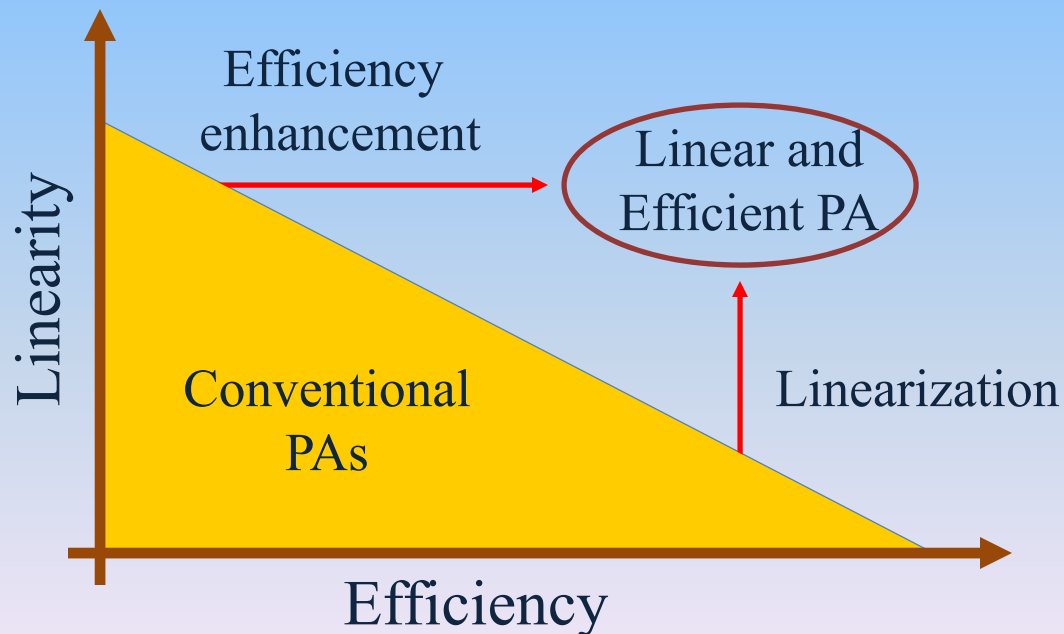
**Input Signal**

**Output Signal of Nonlinear Amplifier  
(with Gain- and Phase-Distortion)**

# PA Design Challenges

## Power Amplifier design challenges:

- **Long talk time**       $\longrightarrow$       **High efficiency**
- **High data rate**       $\longrightarrow$       **High linearity**



# C/I Measure

- **Carrier-to-Intermodulation ratio**
  - **The PA is driven with two or more carriers (tones) of equal amplitude**
  - **IMD will be produced**
    - **Corresponding to sums and differences of multiples of the carrier frequencies**
  - **A typical linear PA has a C/I of 30 dB or better**



# PA Classes

- **Linear operation**
  - **Classes A,B,AB and C**
  - **Amplitude modulation**
  - **Multi-carrier signals**
  - **Transistor works as a transducer**
  - **The RF output power is proportional to the RF input power**
  - **Narrow band and broadband applications**
- **Switching mode (Non-linear)**
  - **Classes D,E,F**
  - **Constant-envelope operation**
  - **Transistor operates as a switch**
  - **Narrow band applications**

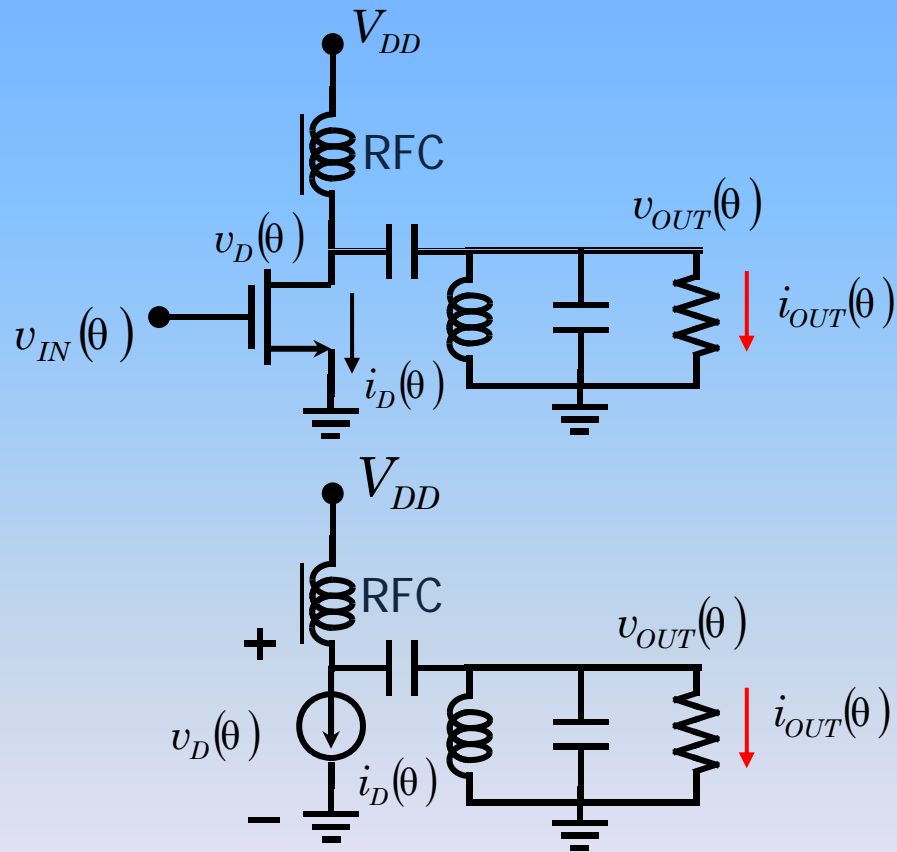
# How preserve Linearity?

- **Backed-Off Operation of PA**
  - **Simplest Way to achieve Linearity**
- **Linearity improving Concepts**
  - **Predistortion**
  - **Feedforward**
  - **EER**
  - ...

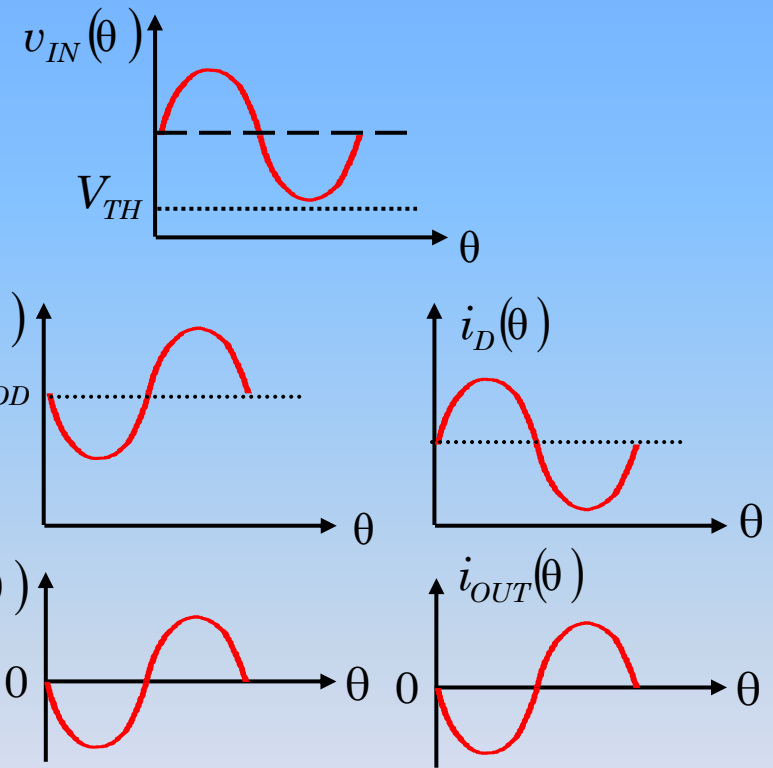
# Basic Linear PA Circuit

ISSCC 2007 GiRaFe Forum

# Class A RF Power Amplifier



$$P_{RFout} = \frac{V_{om}^2}{2R} \leq \frac{V_{DD}^2}{2R}$$



$$\eta_{Drain} = \frac{P_{RFout}}{P_{DC}} = \frac{V_{om}^2 / 2R}{V_{DD}^2 / R} = \frac{V_{om}^2}{2V_{DD}^2} \leq \frac{1}{2}$$

# Class A Characteristics

- **There is no harmonic**
  - Can be used at frequencies near  $f_{\max}$  of the transistor
- **Applications:**
  - High linearity
  - High frequency operation
  - High gain
  - Broadband operation

# Some Practical Considerations

- **Used as low-level driver for efficient PAs**
- **Used for laboratory equipments**
  - **Very low-distortion amplifiers**
- **LC circuit is not necessarily**
  - **Can operate over a wide frequency range**
- **No difference between small signal and class A PA**
- **BJTs have  $V_{sat}$  → limits voltage swing**

# Class A Specifications

- **High linearity**
- **Low drain efficiency of 20-30%**
- **Power added efficiency of 20%**
- **Capable of working at higher frequencies relative to  $f_T$ , up to  $1/2$ - $1/3$  of  $f_T$**
- **Can amplify non-constant envelope signals**
- **Capable of broadband amplification**

# Class A Considerations

- ◆ **Typical efficiency is lower than 40% for “linear” operation**
  - Efficiency actually drops down when the signal level is lower.
- ◆ **Output power capability (transistor utilization factor)**

$$P_N = \frac{P_o}{V_{\max} I_{\max}} = \frac{1}{2} \frac{V_{\max}}{2} \frac{I_{\max}}{2} = \frac{1}{8}$$

- ◆ **Dynamic class A is attractive**



# CLASS A RFPA Performance

# Class B

- **Lower dc current**
  - **Lower power dissipation**
  - **Lower  $f_t$**

# Push-Pull Class B

- **Two devices are driven 180 degrees out-of-phase**
- **They are alternately active or cut-off**

# Class B

- All harmonics exist

*harmonic termination:  
open @  $\omega$ , and short @  $2\omega, 3\omega, \dots$*

*pure sinusoidal waveform  
of current flow*

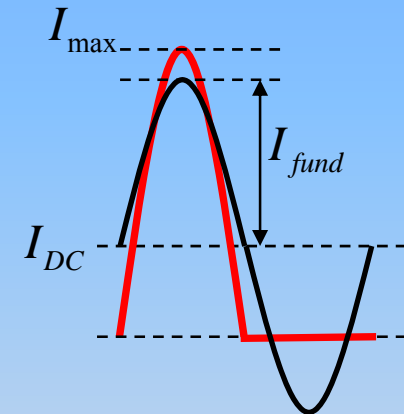
$$I_{fund} = \frac{I_{max}}{2} = I_{CQ,A}$$

$$I_{DC} = \frac{I_{max}}{\pi} < I_{DC,A}$$

$$P_{out,max} = \frac{1}{2} (V_{CEQ} - V_{min}) (I_{fund})$$

$$\eta_{c,max} = \frac{P_{out,max}}{P_{DC}} = \frac{\frac{1}{2} V_{CC} \frac{I_{max}}{2}}{V_{CC} \frac{I_{max}}{\pi}} = 78.5\%$$

$$P_N = \frac{1}{8} \text{ (same as class A)}$$



# Class AB Characteristics

- Conduction angle is between 0 degree and 180 degree

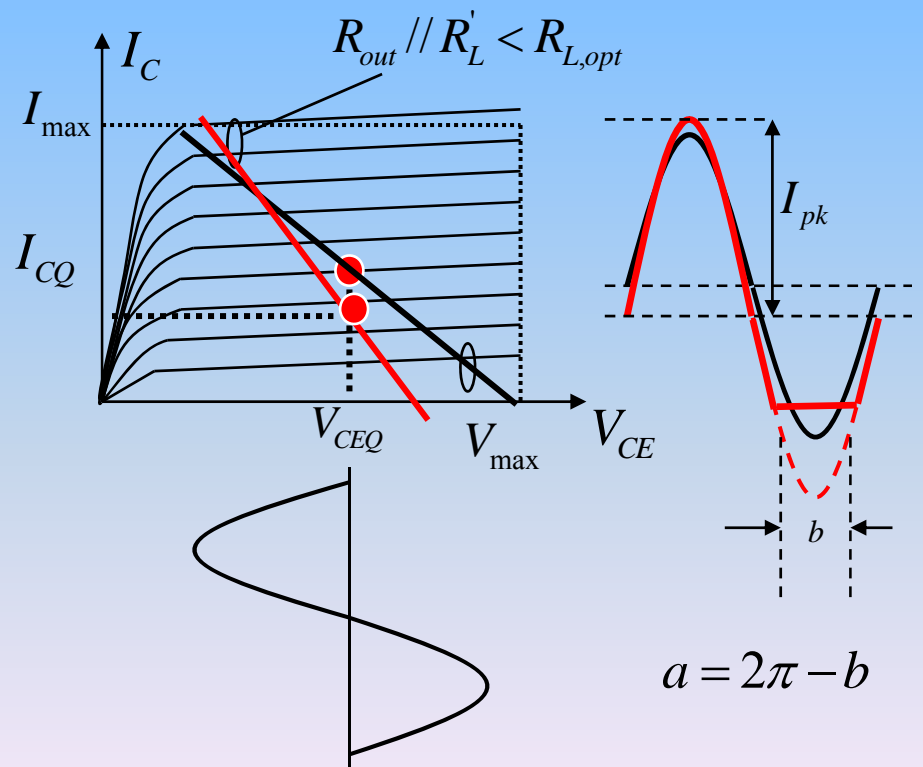
Let  $\theta \equiv \omega_0 t$

$$I(\theta) = \begin{cases} I_{CQ} + I_{pk} \cos\theta & -\frac{a}{2} \leq \theta \leq \frac{a}{2} \\ 0 & \text{theother} \end{cases}$$

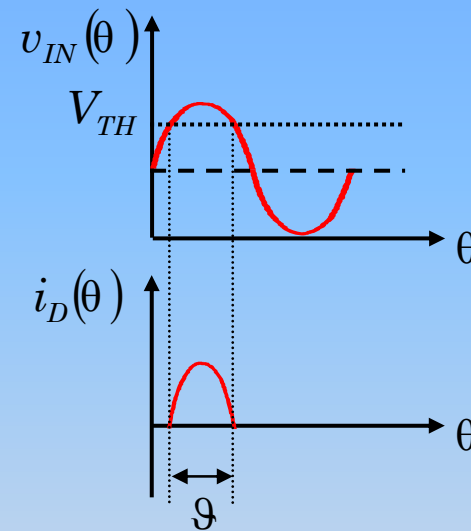
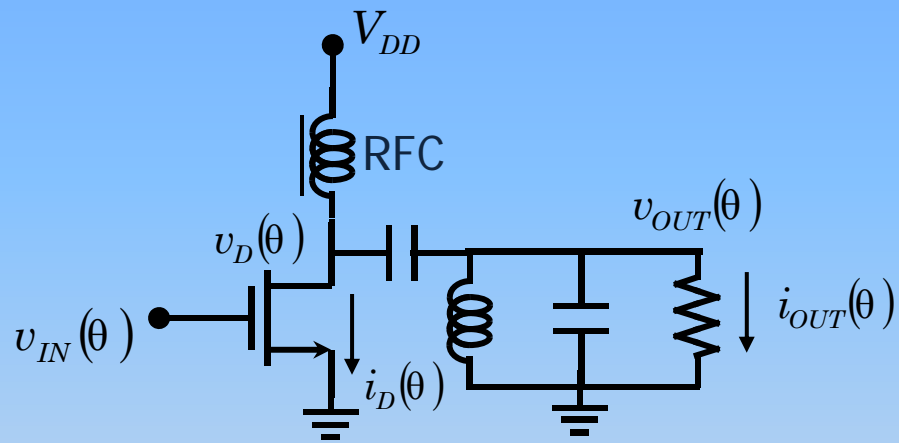
$$\text{From } I_{CQ} + I_{pk} \cos\frac{a}{2} = 0 \Rightarrow \cos\frac{a}{2} = -\frac{I_{CQ}}{I_{pk}}$$

$$\Rightarrow I_{pk} = I_{\max} \frac{1}{1 - \cos\frac{a}{2}}, I_{CQ} = I_{\max} \frac{-\cos\frac{a}{2}}{1 - \cos\frac{a}{2}}$$

$$\Rightarrow I(\theta) = I_{\max} \frac{\cos\theta - \cos\frac{a}{2}}{1 - \cos\frac{a}{2}}$$

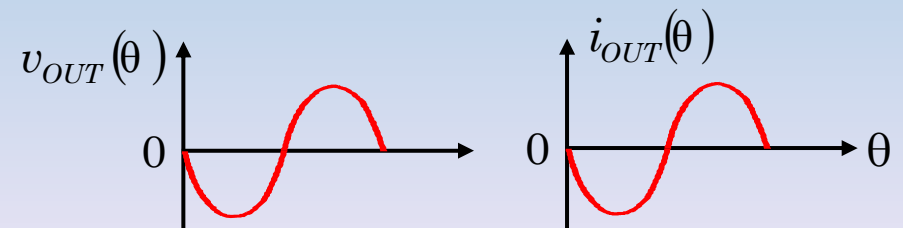


# Class C Amplifier Waveforms



$$P_{RFout} \propto \frac{\vartheta - \sin\vartheta}{1 - \cos(\vartheta/2)}$$

$$\eta_{Drain} = \frac{P_{RFout}}{P_{DC}} = \frac{1}{4} \frac{\vartheta - \sin\vartheta}{\sin(\vartheta/2) - \frac{\vartheta}{2} \cos(\vartheta/2)}$$



# Class C Amplifier

- **Biased such that conduct less than 50% of time**
- **Specifications**
  - **Efficiency achieved**
  - **Large device is needed**
  - **Impractical for solid-state circuit**

# Class C Considerations

- **Higher efficiency, BUT lower output power**
- **Lower output power capability**
  - Maximum @ 245.2 degrees →  $C_p=0.1341$
- **The choice of conduction angle is trade off between**
  - Output power
  - Efficiency
  - Power gain

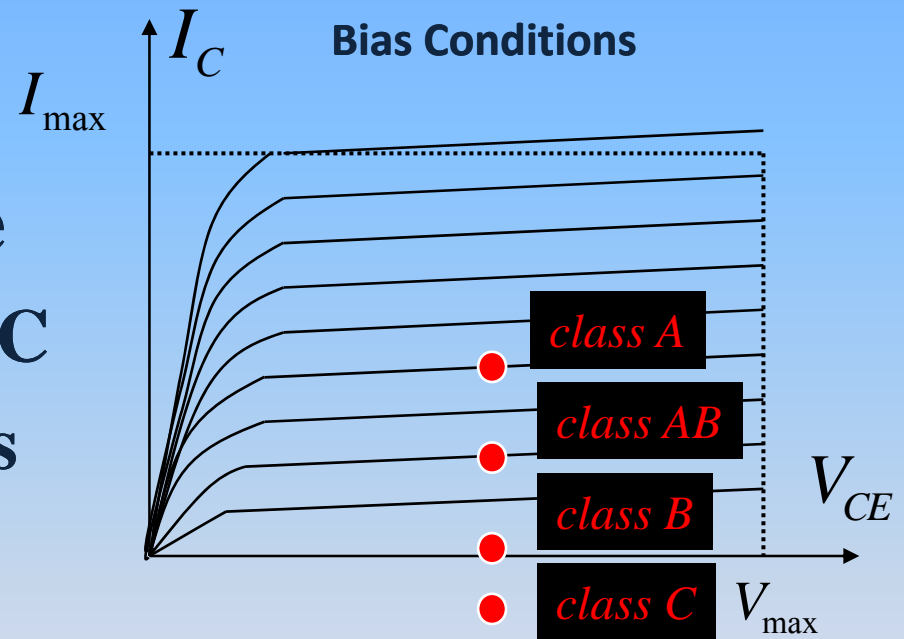


# Types of Class C

- **There are 3 types**
  - **Current-Source Class C Amplifiers**
    - **Transistor never saturates**
    - **Acts as controlled-current source**
  - **Saturated Class-C Amplifiers**
    - **Transistor acts in saturation region in a portion of conduction**
  - **Class C Mixed Mode Amplifiers**

# Comparison

- **From class A to C bias current will be decrease**
  - Lower  $f_t$  from class A to C
  - **BUT, efficiency increases**



# Comparison

# Comparison

# COMPARISON

- Numerical value of PA under different operation

	<b>Class A</b>	<b>Mid-Class AB</b>	<b>Class B</b>	<b>Mid-class C</b>	<b>Class C</b>
<b><i>b</i></b>	<b>0</b>	<b>90</b>	<b>180</b>	<b>270</b>	<b>360</b>
<b><i>I<sub>cQ</sub></i></b>	<b><math>I_{max}/2</math></b>	<b><math>0.41 \cdot I_{max}</math></b>	<b>0</b>	<b>0</b>	<b>0</b>
<b><i>I<sub>DC</sub></i></b>	<b><math>I_{max}/2</math></b>	<b><math>0.44 \cdot I_{max}</math></b>	<b><math>I_{max}/\pi</math></b>	<b><math>0.16 \cdot I_{max}</math></b>	<b>0</b>
<b><i>I<sub>fund</sub></i></b>	<b><math>I_{max}/2</math></b>	<b><math>0.53 \cdot I_{max}</math></b>	<b><math>I_{max}/2</math></b>	<b><math>0.31 \cdot I_{max}</math></b>	<b>0</b>
<b><math>\eta_{c,max}</math></b>	<b>50%</b>	<b>60%</b>	<b>78.5%</b>	<b>~100%</b>	<b>(~100%)</b>

# SMIPA

- **Major part of power dissipation is due to transistors**
- **Single pole-single through switch is used**

# SMIPA

*Voltage and current waveforms in a switching-mode amplifier*

# SMIPA



# SMIPA IDEA

- **Filter is used**
  - **Parallel LC shunt**
  - **Series LC tuned**
- **Filter increases the efficiency**

# **SMPA Idea**

- **Parallel LC filter**

# **SMPA Idea**

- **Series LC tuned filter**

# General SMPA switching conditions

- **Two models:**

A

B

- **Model A is better**

$$P_{C,Loss} = \frac{1}{2} \cdot C \cdot V_c^2 \cdot f \quad P_{L,Loss} = \frac{1}{2} \cdot L \cdot I_L^2 \cdot f$$

- **Minimization of losses at RF requires:**
  - $V_c = 0$  when switch closes at  $t = 0$ 
    - **Zero voltage switching condition (ZVS)**
  - **Even better:  $dV_c/dt = 0$**

# Class D Power Amplifier

- **Transistors act as to pole switch**
- **Suffers from losses**
  - **Saturation**
  - **Switching speed**
  - **Drain capacitor**
    - **Dissipation occurs**
      - **Proportional with F**
      - **Limited to VHF**

# Other Categories

- **Complementary Voltage Switching (CVS) Circuit**
- **Transformer-Coupled Voltage Switching (TCVS) Circuit**
- **Transformer-Coupled Current Switching (TCCS) Circuit**

# CVS Class D

- **Parallel LC can not be used**
- **In ideal condition**
  - **Zero saturation voltage**
  - **Zero saturation resistance**
  - **Infinite OFF resistance**
  - **Instantaneous and lossless switching**

# CVS Waveforms

➤ **Switch capacitance limits efficiency in high frequency applications**



# Class-D and Class-D<sup>-1</sup> Amplifiers

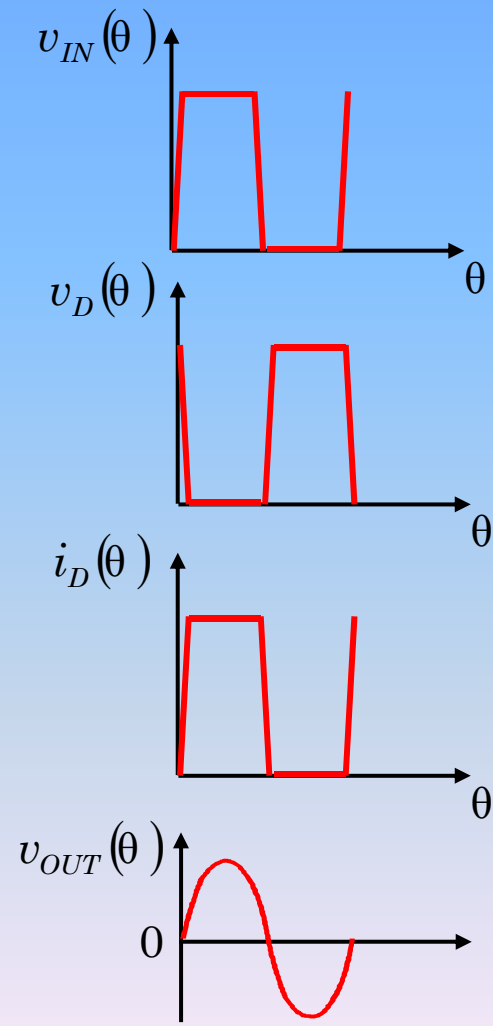
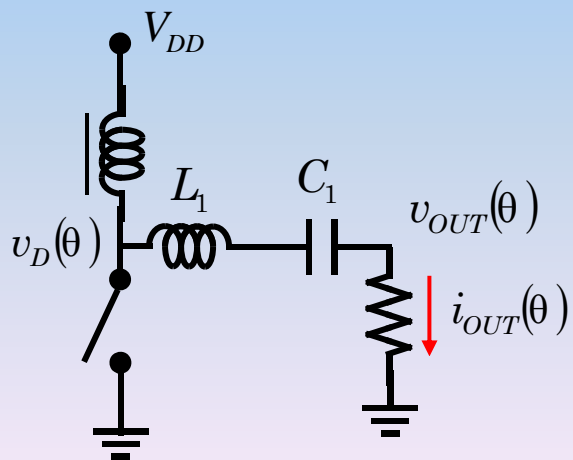
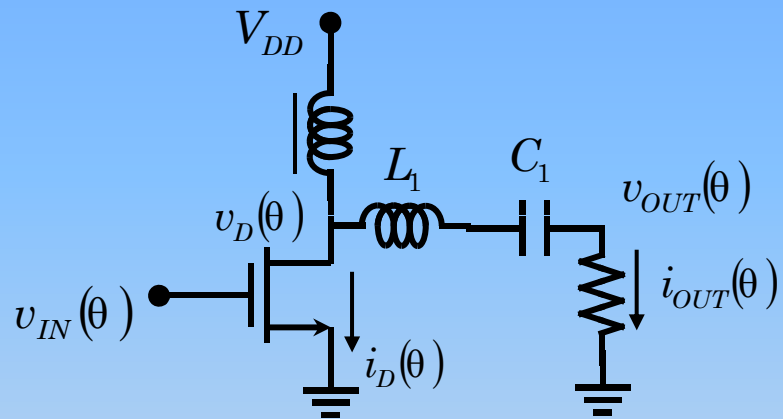
# TCVS

# TCCS

# Class D Specifications

- **Very low linearity**
  - **Can not amplify non-constant envelope signals**
- **High drain efficiency (60%)**
- **Moderate power added efficiency(40%)**
- **Can only be used for narrow-band amplification**
- **Proper for low frequency operation**

# Class E Power Amplifiers



# Class E

- **Transistor acts as a switch**
- **Conditions**
  - **Turn on**
    - **The drain voltage drops to zero**
    - **Zero voltage slope**
      - **Transistor current is zero @ off → on**
      - **Helps to minimize transition time**
  - **Turn off**
    - **Zero current**
    - **Zero current slope**

# Class E

- **Trade-off between efficiency and output harmonic content**

$$L = \frac{QR_L}{\omega} \quad C_1 = \frac{1}{5.447 \cdot \omega R_L}$$

$$C_2 = \frac{1}{\omega^2 L} \left( 1 + \frac{1.42}{Q_L - 2.08} \right)$$

$$P_N \approx 0.098$$

# Important Considerations

- **Shunt capacitance is important**
  - It does not allow a fast rise of the collector voltage
- **Shunt capacitance is voltage dependent**
  - One of non-idealities
- **No current jump at turn-on transition**
  - Reduce the power loss



# Practical Considerations

- **Real transistor has**
  - **Non-zero switching time**
  - **Parasitic reactance**
  - **Non-zero ON resistance**
    - **Saturation voltage for BJTs**
- **No pure sine wave current @ the output**
- **Finite Q-factor of reactive components**
- **Maximum Drain voltage is “3.6\*VDD”**

# Class E Amplifier Design and Efficiency

- **Non-idealities of class E**
  - ON resistance
  - Off-transients
    - Efficiency will be reduced
- **Normalized Output Power Capability**

$$v_{DS,\max} \approx 3.6V_{DD}, i_{D,\max} \approx 1.7 \frac{V_{DD}}{R}$$

$$P_{L,\max} = \frac{2}{1 + \frac{\pi^2}{4}} \approx 0.577 \cdot \frac{V_{DD}^2}{R} \Rightarrow P_N = \frac{P_{L,\max}}{v_{DS,\max} \cdot i_{D,\max}} \approx 0.098$$

# Class F Amplifiers

- **Harmonic manipulation is used to shape voltage and current signals**

Class F Schematic

# Class F Operation

# Class F Operation

- A Parallel LC resonator is used instead of Quarter-wave length transmission line.

# Class F Power Amplifier Analysis

$$v_{fund} = \frac{4}{\pi} \cdot V_{DD}$$

**Power delivered to the load:**

$$P_L = \frac{v_{fund}^2}{2R} = \frac{8V_{DD}^2}{\pi^2 R}$$

$$i_{D,max} = \frac{4}{\pi} \cdot \frac{2V_{DD}}{\pi R}, v_{DS,max} = 2V_{DD}$$

$$P_N = \frac{v_{fund}^2}{2R} = \frac{8V_{DD}^2}{\pi^2 R} / \left( 2V_{DD} \cdot \frac{8V_{DD}}{\pi R} \right) = \frac{1}{2\pi} \approx 0.16$$

# Other Type of Class F

*Waveforms in a second-harmonic peaking  
Class F1 amplifier*

# Class F Efficiency

- **In theory, if you can control an infinite number of harmonics, efficiency approaches 100%**



# Class F Disadvantages

- **Output capacitance of device not naturally absorbed into network → need inductor to tune it out**
- **Difficult to control more than 5<sup>th</sup> harmonic ... resonators are lossy and additional losses present diminishing returns on efficiency.**

# Comparison

- **Achievable Efficiencies of PAs**

# PA CLASSIFICATION

# Traditional PA Classification

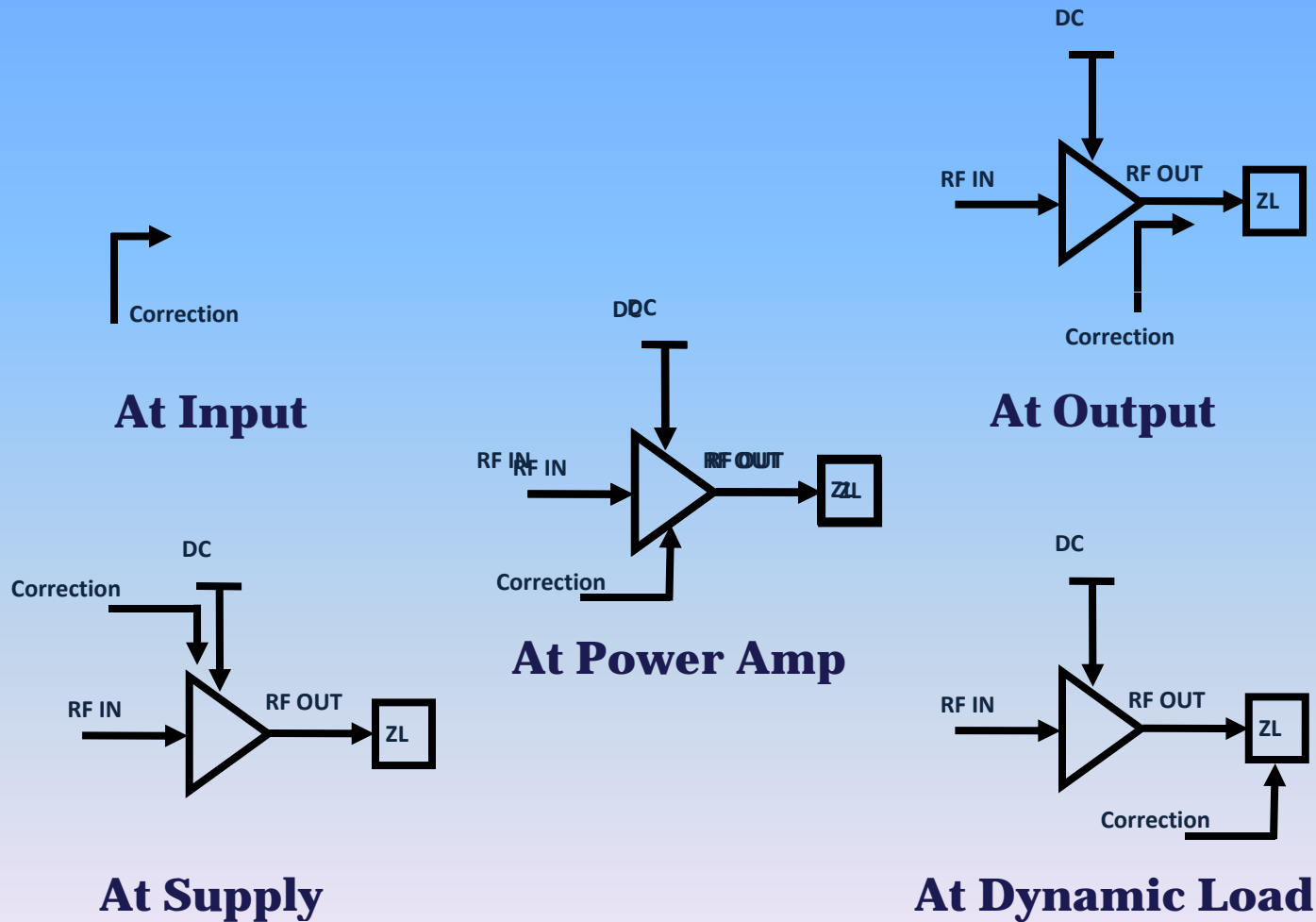
# Summary of a few basic PA measures for classes A-F

# Linearization Techniques

# Linearization Techniques

- **Linearization techniques:**  
“... utilized in complex , expensive RF and microwave systems, but they have not yet found their way into low-cost portable terminals.” B. Razavi, *RF Microelectronics*.
- **Most linear PAs in portable phones**  
→ class A stages with “backed off”

# Linearization Schemes



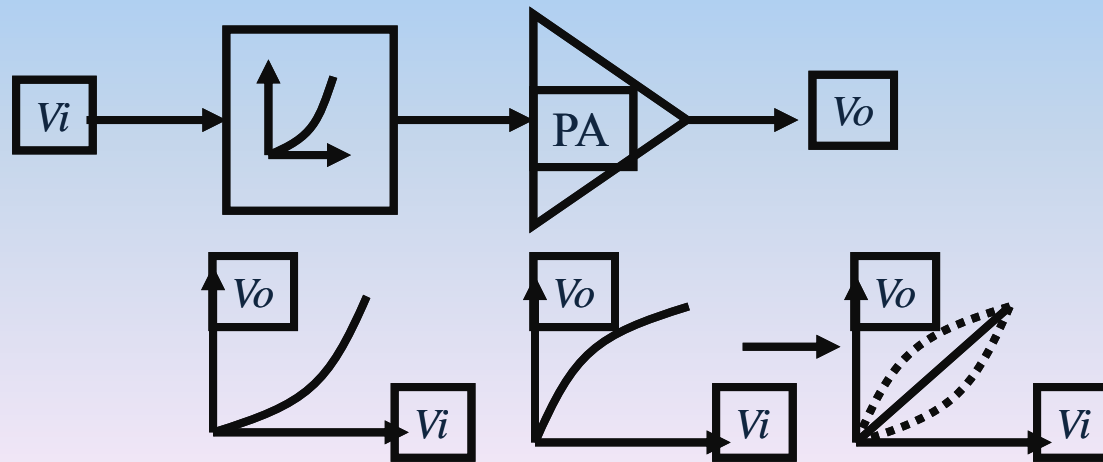


# Correct Nonlinearity at Input

- **Predistortion**
  - **Close loop( Adaptive PreDistortion)**
  - **Open loop**
- **Feedback**
  - **Direct Feedback**
  - **Cartesian**
  - **Polar**

# PreDistortion

- **RF/ IF/ base band**
- **Insertion a nonlinear element before PA**
- **Amplitude and/or phase correction.**
- **Improvement in ACPR by 10 dB is typical.**



# AM/AM & AM/PM Distortion

# Open Loop PreDistortion

- **Require Characteristics of PA**
- **Lookup table for base-band or RF**
- **Difficulties in**
  - **Resolution**
  - **Tolerances**
  - **Long term drift in characteristics**

# Table Based Predistortion

- **Polar Predistortion by Amplitude**

# Table Based Predistortion

- **Full Cartesian Predistortion**

# Closed Loop PreDistortion

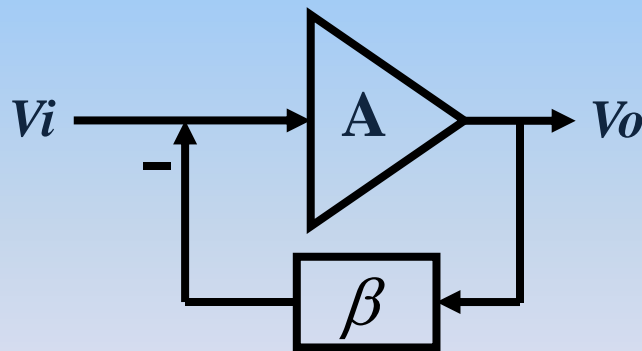
- **Difficulties in Resolution**
- **Corrects for long term drift and slowly changing amplifier behaviors /temperature /etc.**

# PreDistortion Example



# Direct Feedback

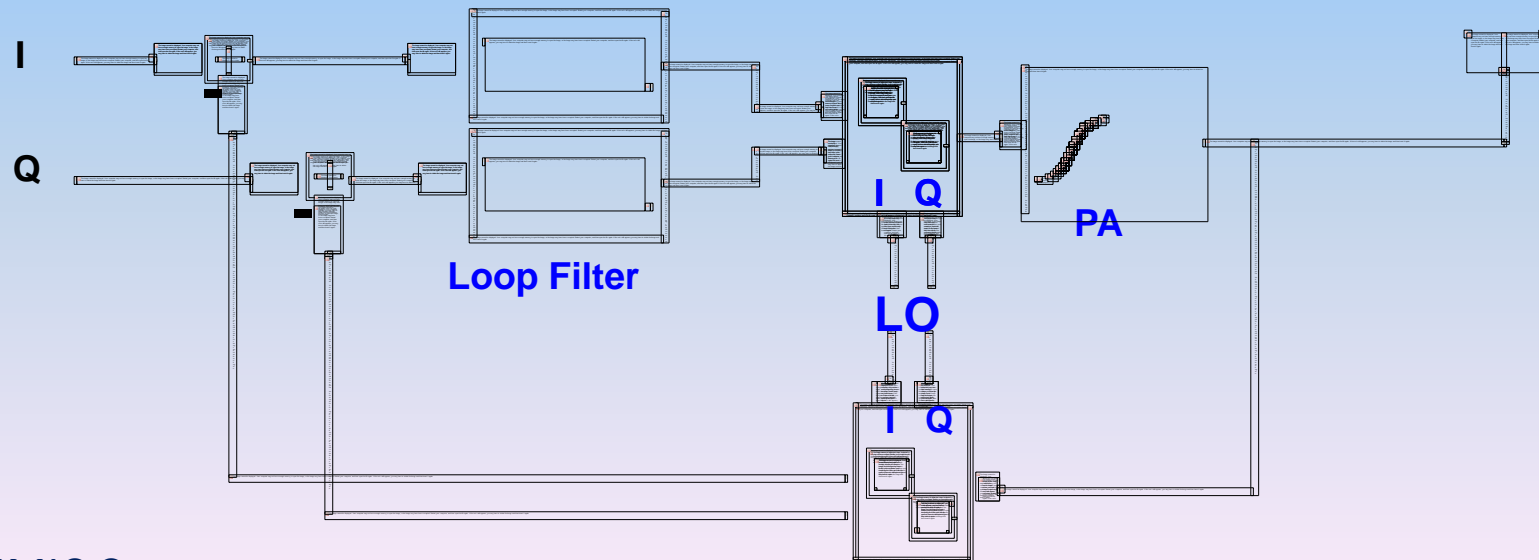
- **Basic negative feedback technique to improve linearity**
- **High loop gain yields to better linearity**
- **Signal gain drop and excess phase shift**
- **Stability Check**



$$G = \frac{V_o}{V_i} = \frac{A}{1 + \beta A}$$

# Cartesian Feedback

- **W: Bandwidth Limitation**
- **W: Stability concerns**
- **S: Low-Complexity & power efficient**
- **S: Highly resistant to drift and aging**
- **Ss: Robust to poor characterization of PA**



# Polar Feedback

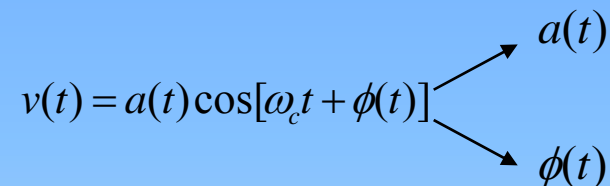
- **W: Bandwidth Limitation & Stability concerns**
- **S: Low-Complexity**
- **S: Highly resistant to drift and aging**
- **Ss: Robust to poor characterization of PA**

# Correct Nonlinearity at Supply

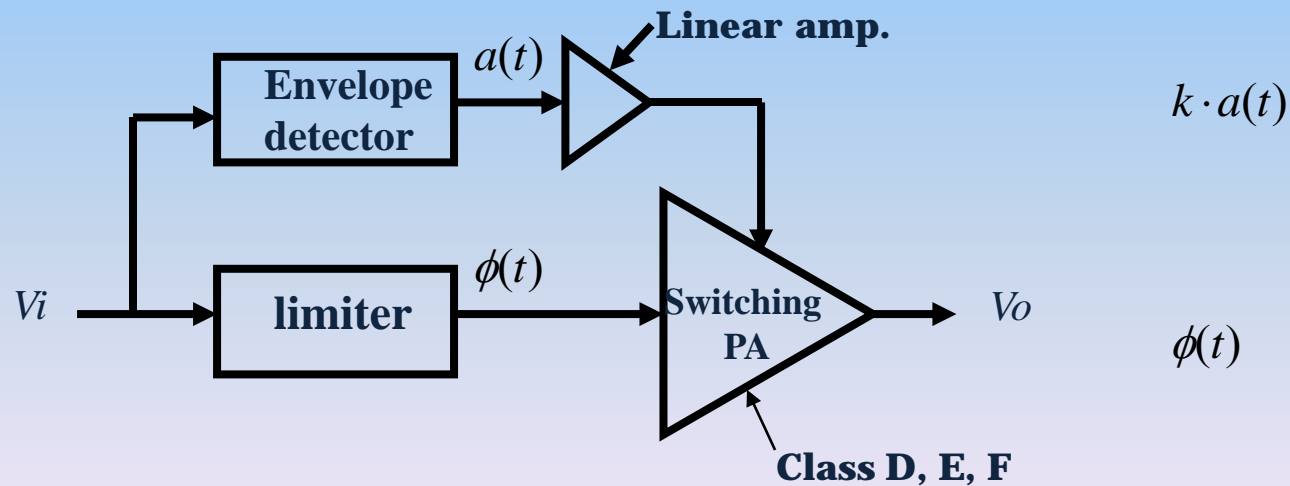
- **Envelope Elimination And Restoration(EER)**
- **Dynamic Supply/ Envelope Tracking**

# Envelope Elimination and Restoration (EER)

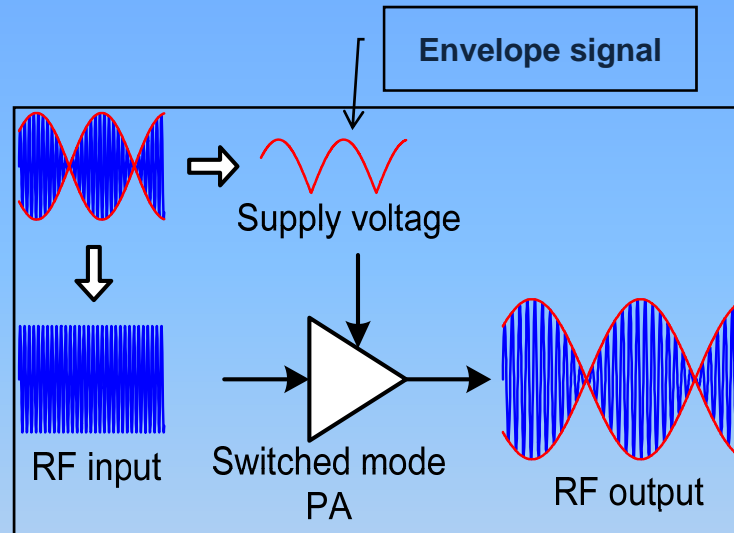
- Decompose a bandpass signal into an envelope signal and a phase signal

$$v(t) = a(t) \cos[\omega_c t + \phi(t)]$$


- Require no linearity in PA stage.



# Envelope Signal



# Closed-Loop EER Implementation

# Envelope Detector

- **Non Ideal Diode → Using this circuit**



# Envelope Amplifier

- **High efficiency envelope amplifier is required**
  - **Bandwidth: > 20 MHz for 5 MHz signal**
  - **High Current**
  - **Efficiency: >>50%**
- **Problems**
  - **Complicated circuit**
  - **Limited bandwidth**

# Influence of time alignment

- **Misalignment between amplitude and phase paths**
  - Leads to severe signal distortion
  - Alignment requirements in the order of a few psec.

# Influence of time alignment

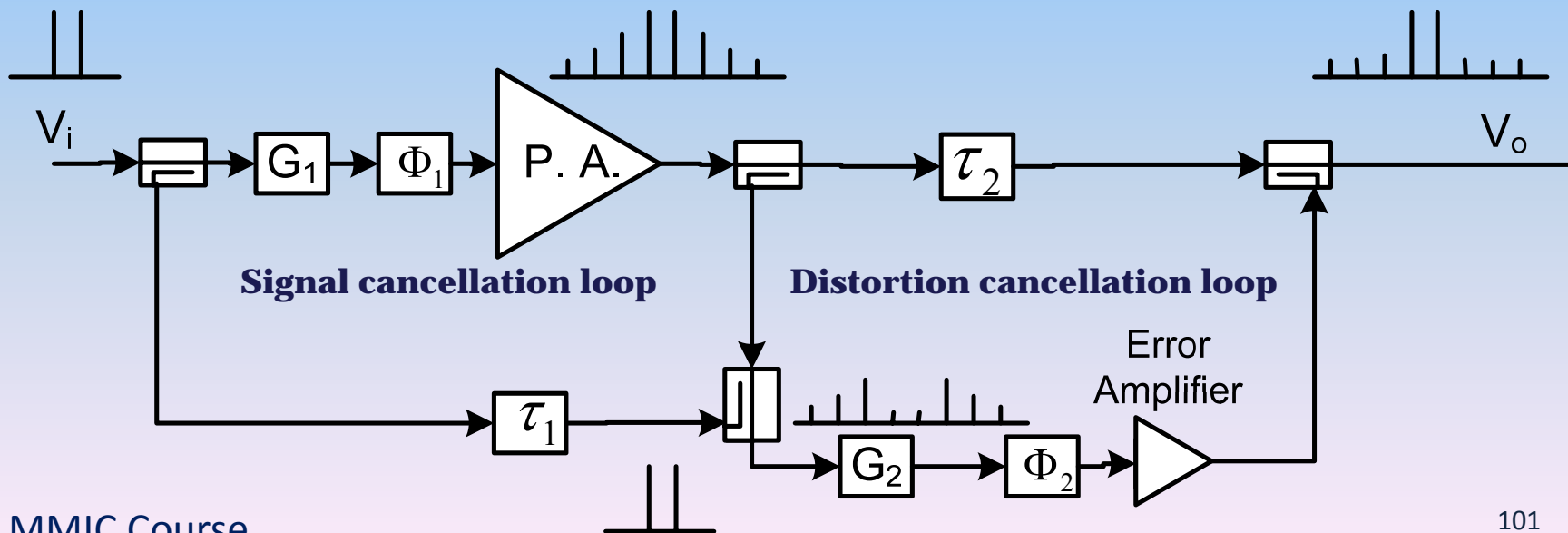
- **Misalignment between amplitude and phase paths**
  - Leads to severe signal distortion
  - Alignment requirements in the order of a few psec.

# EER Issues

- **Require Envelope amplifier  
(drain DC supply)**
- **Mismatch of gain and phase between two paths**
- **Limiter exhibits AM/PM Distortion**
- **Efficiency of Switching Power Supply**
- **Band Width of Switching Power Supply**
- **Time alignment between the supply and RF paths**

# Feed Forward

- **Correct non-linearity at output**
- **Two loops**
  - **Signal Cancellation loop**
  - **Distortion Cancellation loop**



# Feed Forward

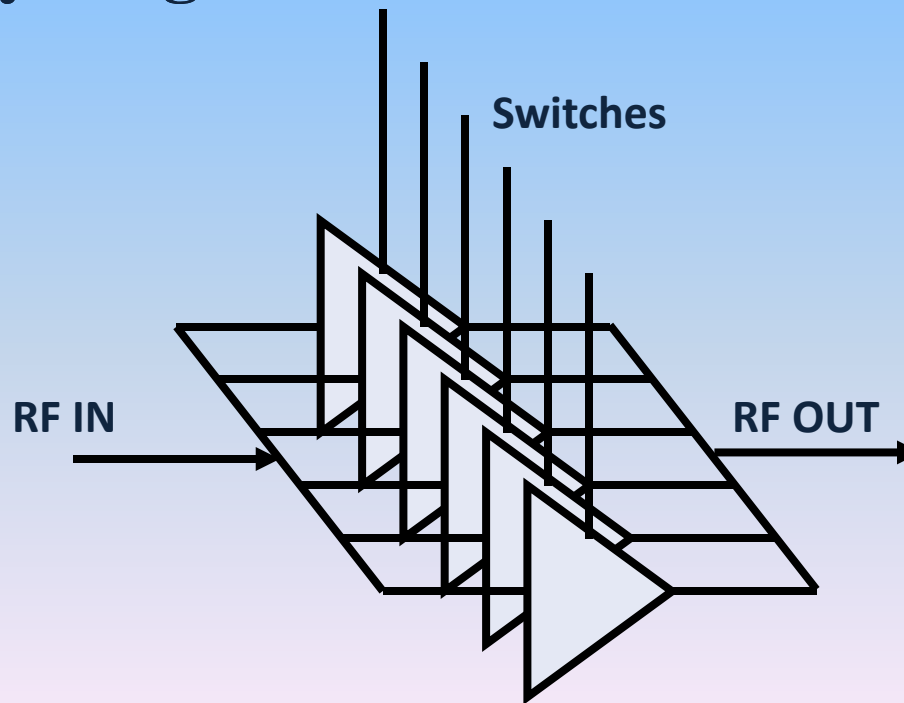
- **Advantages:**
  - Wide bandwidth
  - Good Cancellation performance
- **Issues:**
  - Difficult to build analog delay elements.
  - Requires low loss output “adder/coupler”.
  - Sensitive to amplitude and phase imbalance due to process and temperature variation..
  - High complexity

# Adaptive Feed Forward

- **Open loop → Close loop FF**
- **Robust to poor characterization of PA**

# Array of Power Amps

- **Array of Power Amps are used**
  - **Similar**
  - **Binary weighted**





*Thanks for your time!*